Image Reject Mixer 12.0-40.0 GHz

Features

- Fundamental Image Reject Mixer
- 8.0 dB Conversion Loss
- 20.0 dB Image Rejection
- +25.0 dBm Input Third Order Intercept (IIP3)
- 100% On-Wafer RF Testing
- 100% Visual Inspection to MIL-STD-883 Method 2010
- RoHS* Compliant and 260°C Reflow Compatible

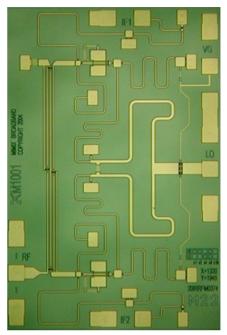
Description

M/A-COM Tech's 12.0-40.0 GHz GaAs MMIC fundamental image reject mixer can be used as an up- or down-converter. The device has a conversion loss of 8.0 dB with a 20.0 dB image rejection across the band. I and Q mixer outputs are provided and an external 90 degree hybrid is required to select the desired sideband. This MMIC uses M/A-COM Tech's GaAs PHEMT device model technology, and is based upon electron beam lithography to ensure high repeatability and uniformity. The chip has surface passivation to protect and provide a rugged part with backside via holes and gold metallization to allow either a conductive epoxy or eutectic solder die attach process. This device is well suited for Millimeter-wave Point-to-Point Radio, LMDS, SATCOM and VSAT applications.

Ordering Information

Part Number	Package		
XM1001-BD-000V	"V" - vacuum release gel paks		
XM1001-BD-EV1	evaluation module		

Chip Device Layout



Absolute Maximum Ratings

Parameter	Absolute Max.	
Gate Bias Voltage (Vg)	+0.3 VDC	
Input Power (RF Pin)	+20.0 dBm	
Input Power (IF Pin)	+20.0 dBm	
Storage Temperature (Tstg)	-65 °C to +165 °C	
Operating Temperature (Ta)	-55 °C to +125 °C	

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Electrical Specifications: 12-40 GHz (Upper Side Band) (Ambient Temperature T = 25°C)

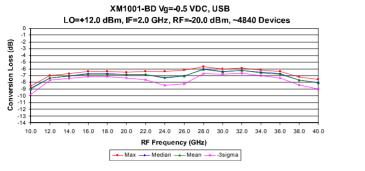
		•	
Units	Min.	Тур.	Max.
GHz	12.0	-	38.0
GHz	8.0	-	42.0
GHz	DC	-	4.0
dB	-	10.0	-
dB	-	TBD	-
dB	-	TBD	-
dB	-	8.0	-
dBm	-	+12.0	-
dBc	-	20.0	-
dB	-	16.0	-
dB	-	TBD	-
dB	-	TBD	-
dBm	-	+25.0	-
VDC	-2.0	-0.5	+0.1
	GHz GHz GHz dB dB dB dB dB dB dB dB dB dB dB dB dB	GHz 12.0 GHz 8.0 GHz DC GHz DC dB - dB -	GHz 12.0 - GHz 8.0 - GHz DC - dB - 10.0 dB - TBD dB - TBD dB - TBD dB - 8.0 dB - 10.0 dB - 700 dB - 700<

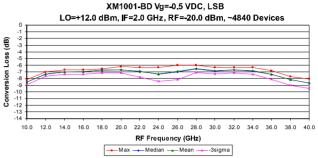


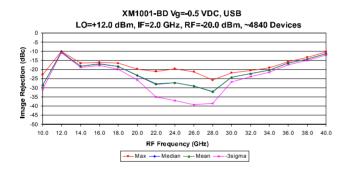
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Typical Performance Curves







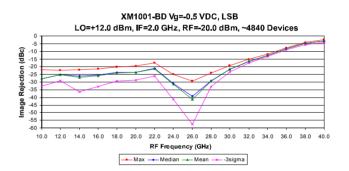


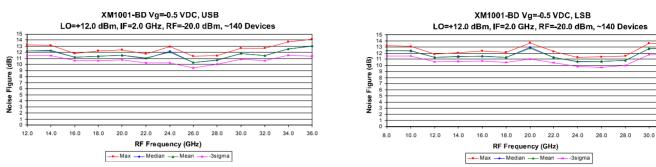


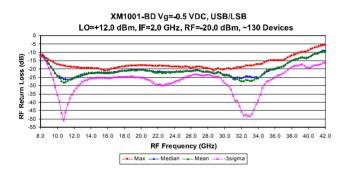
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Typical Performance Curves (cont.)





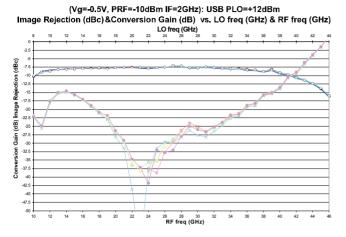
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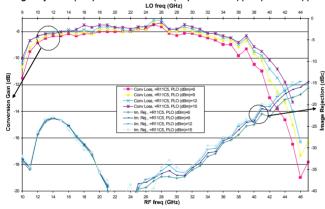
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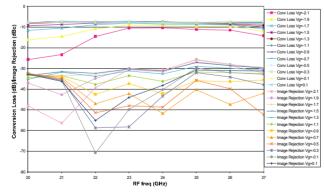
Typical Performance Curves (cont.)



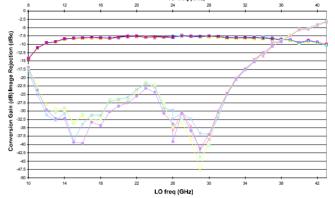
(USB, Vg=-0.5V, PRF=-10dBm, IF=2GHz): 1 device and different powers Image Rejection (dBc) &Conversion Gain (dB) vs. LO freq (GHz) & RF freq (GHz)



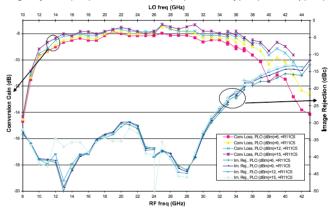
USB Conversion Gain/Image Rejection vs Frequency and for differents Vg bias (-2.1V to 0.1V with 0.2V steps) PLO=+12dBm

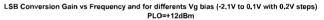


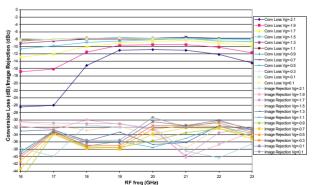
(Vg=-0.5V, PRF=-10dBm IF=2GHz): LSB PLO=+12dBm Image Rejection (dBc) & Conversion Gain(dB) vs. LO freq (GHz) & RF freq (GHz) RF freq (GHz)



(LSB, Vg=-0.5V, PRF=-10dBm, IF=2GHz): 1 device and different powers Image Rejection (dBc) &Conversion Gain (dB) vs. LO freq (GHz) & RF freq (GHz)







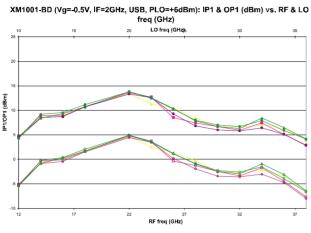
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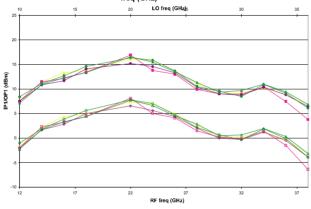
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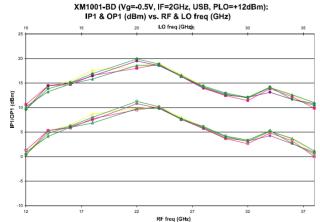
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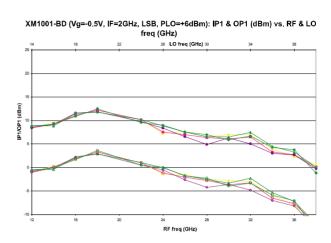
Typical Performance Curves (cont.)



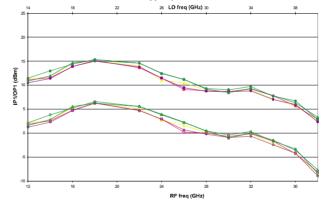
XM1001-BD (Vg=-0.5V, IF=2GHz, USB, PLO=+9dBm): IP1 & OP1 (dBm) vs. RF & LO freq (GHz)

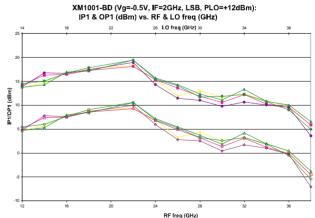






XM1001-BD (Vg=-0.5V, IF=2GHz, LSB, PLO=+9dBm): IP1 & OP1 (dBm) vs. RF & LO freq (GHz)





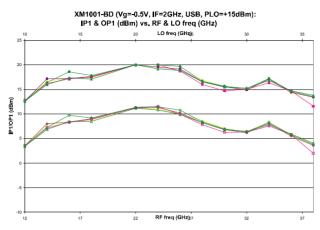
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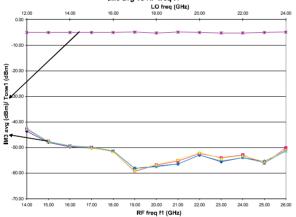
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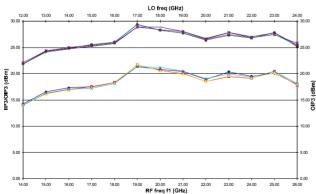
Typical Performance Curves (cont.)

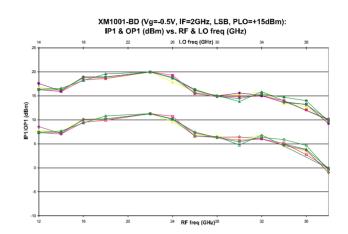


XM1001-BD (Vg=-0.5V, IF=2GHz, LO=+12dBm, IF14F2=100MHz, USB, Down Conversion): IM3 avg vs RF freq f1

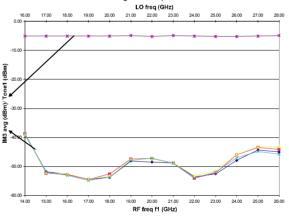


XM1001-BD (Vg=-0.5V, IF=2GHz, LO=+12dBm, IF1-IF2=100MHz, USB, Down Conversion): OIP3 avg vs RF freq f1, IIP3 vs RF freq f1

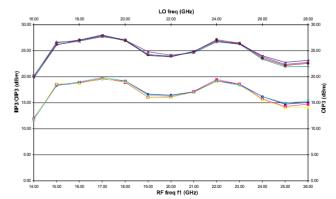




XM1001-BD (Vg=-0.5V, IF=2GHz, LO=+12dBm, IF1-IF2=100MHz, LSB, Down Conversion): IM3 avg vs RF freq f1



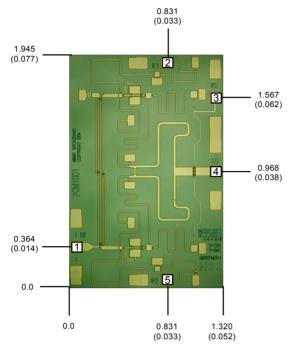
XM1001-BD (Vg=-0.5V, IF=2GHz, LO=+12dBm, IF1-IF2=100MHz, LSB, Down Conversion): OIP3 avg vs RF freq f1, IIP3 vs RF freq f1



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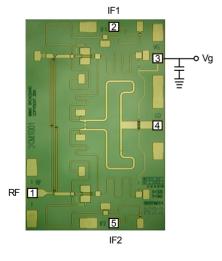
Mechanical Drawing



(Note: Engineering designator is 20IRRFM0374)

Units: millimeters (inches) Bond pad dimensions are shown to center of bond pad. Thickness: 0.110 +/- 0.010 (0.0043 +/- 0.0004), Backside is ground, Bond Pad/Backside Metallization: Gold All Bond Pads are 0.100 x 0.100 (0.004 x 0.004). Bond pad centers are approximately 0.109 (0.004) from the edge of the chip. Dicing tolerance: +/- 0.005 (+/- 0.0002). Approximate weight: 1.592 mg. Bond Pad #1 (RF) Bond Pad #3 (Vg) Bond Pad #5 (IF2) Bond Pad #2 (IF1) Bond Pad #4 (LO)

Bias Arrangement



Bypass Capacitors - See App Note [2]

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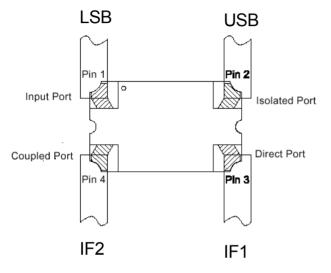
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App Note [1] Biasing - As shown in the bonding diagram, the pHEMT mixer devices are operated using a separate gate voltage Vg1. Set Vg1=-0.5V for optimum conversion loss performance.

App Note [2] Bias Arrangement - Each DC pad (Vg1) needs to have DC bypass capacitance (~100-200 pF) as close to the device as possible. Additional DC bypass capacitance (~0.01 uF) is also recommended.

App Note [3] USB/LSB Selection -

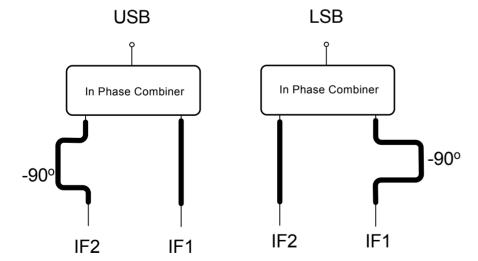


An alternate method of Selection of USB or LSB:

For Upper Side Band Operation (USB): With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the USB signal will reside on the isolated port. The input port must be loaded with 50 ohms.

For Lower Side Band Operation (LSB): With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the LSB signal will reside on the input port. The isolated port must be loaded with 50 ohms.

Note: The coupled port can be used as an alternative input but the port location of the Coupled and Direct ports reverse.



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Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices. Rev. V1



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